IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Satoshi KAMIYAMA et al.

10/500002

Serial Number: Not Yet Assigned

(§371 of international application No. PCT/JP02/13735)

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For: GROUP III-NITRIDE SEMICONDUCTOR SUBSTRATE AND PRODUCTION

METHOD

Attorney Docket No.: 042398

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INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P. O. Box 1450 Alexandria, VA 22313-1450

June 23, 2004

Sir:

In compliance with 37 CFR 1.56, Applicants call to the attention of the Patent and Trademark Office the references listed on the attached PTO-1449.

A copy of each of the references is enclosed herewith.

In the event there are any fees due in connection with the filing of this paper, please charge Deposit Account No. <u>50-2866</u>.

Respectfully submitted, WESTERMAN, HATTORI, DANIELS & ADRIAN, LLP

Sadao Kinashi

Reg. No. 48,075

1250 Connecticut Avenue, N.W., Suite 700

Washington, D.C. 20036 Tele: (202) 822-1100

Fax: (202) 822-1111

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Enclosures: PTO-1449; References (9) and international search report.



INFORMATION
DISCLOSURE
STATEMENT
PTO-1449

Atty. Docket No. 042398

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Applicant(s): Satoshi KAMIYAMA et al.

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Group Art Unit:

FOREIGN PATENT DOCUMENTS

		Document No.	Date	Country	Translation (Yes or No)
	AA	EP1 176 231	01/30/02	EPO	Yes. Cited in the int'l. search report.

OTHER DOCUMENTS

	AB	Patent Abstracts of Japan, Publication No.: 2003-104800, dated 04/09/03. Cited in the int'l. search report.
	AC	Patent Abstracts of Japan, Publication No.: 10-095699, dated 04/14/98. Cited in the specification.
	AD	Patent Abstracts of Japan, Publication No.: 11-162847, dated 06/18/99. Cited in the specification.
	AE	Patent Abstracts of Japan, Publication No.:11-103135, dated 04/13/99. Cited in the specification.
	AF	Patent Abstracts of Japan, Publication No.:11-251253, dated 09/17/99. Cited in the specification.
	AG	Patent Abstracts of Japan, Publication No.:2001-060719, dated 03/06/01. Cited in the specification.
	AH	Patent Abstracts of Japan, Publication No.:2001-308464, dated 11/02/01. Cited in the specification.
	AI	Hiroyuki KINOSHITA et al; Japan Journal of Applied Physics, Vol. 40, Part 2, No. 12A, pp. L1280-L1282. Dec. 1, 2001. Cited in the specification.
Examiner		Date Considered